



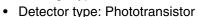
Transmissive Optical Sensor with Phototransistor Output

Description

The TCST1230 is a transmissive sensor that includes an infrared emitter and phototransistor, located faceto-face on the optical axes in a leaded package which blocks visible light.

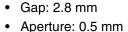
Features

· Package type: Leaded





L 9.2 mm x W 4.8 mm x H 5.4 mm



Typical output current under test: I_C = 2 mA

· Daylight blocking filter

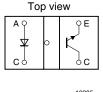
• Emitter wavelength: 950 nm

• Lead (Pb)-free soldering released

• Lead (Pb)-free component in accordance with RoHS 2002/95/EC and WEEE 2002/96/EC

• Minimum order quantity: 4800 pcs, 60 pcs/tube





Applications

- · Optical switch
- · Shaft encoder
- · Detection of opaque material such as paper
- Detection of magnetic tapes

Absolute Maximum Ratings

 T_{amb} = 25 °C, unless otherwise specified

Coupler

Parameter	Test condition	Symbol	Value	Unit
Total power dissipation	T _{amb} ≤ 25 °C	P _{tot}	250	mW
Operation temperature range		T _{amb}	- 25 to + 85	°C
Storage temperature range		T _{stg}	- 40 to + 100	°C
Soldering temperature	Distance to package 1.6 mm, $t \le 5$ s	T _{sd}	260	°C

Input (Emitter)

Parameter	Test condition	Symbol	Symbol Value L	
Reverse voltage		V_{R}	6	V
Forward current		I _F	60	mA
Forward surge current	$t_p \le 10 \mu A$	I _{FSM}	3	Α
Power dissipation	T _{amb} ≤ 25 °C	P _V	100	mW
Junction temperature		T _j	100	°C

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Output (Detector)

Parameter	Test condition	Symbol	Value	Unit
Collector emitter voltage		V_{CEO}	70	V
Emitter collector voltage		V _{ECO}	7	V
Collector current		I _C	100	mA
Power dissipation	T _{amb} ≤ 25 °C	P_V	150	mW
Junction temperature		T _j	100	°C

Electrical Characteristics

 T_{amb} = 25 °C, unless otherwise specified

Coupler

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Collector current	$V_{CE} = 10 \text{ V}, I_{F} = 20 \text{ mA}$	I _C	0.5		14	mA
Collector emitter saturation voltage	$I_F = 20 \text{ mA}, I_C = 0.2 \text{ mA}$	V _{CEsat}			0.4	V

Input (Emitter)

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Forward voltage	I _F = 60 mA	V _F		1.25	1.5	V
Junction capacitance	$V_R = 0$, $f = 1 MHz$	C _j		50		pF

Output (Detector)

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Collector emittter voltage	I _C = 1 mA	V_{CEO}	70			V
Emitter collector voltage	I _E = 10 μA	V _{ECO}	7			V
Collector dark current	$V_{CE} = 25 \text{ V}, I_F = 0, E = 0$	I _{CEO}		10	100	nA

Switching Characteristics

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Turn-on time	I_C = 1 mA, V_{CE} = 5 V, R_L = 100 Ω (see figure 1)	t _{on}		15.0		μѕ
Turn-off time	I_C = 1 mA, V_{CE} = 5 V, R_L = 100 Ω (see figure 1)	t _{off}		10.0		μs

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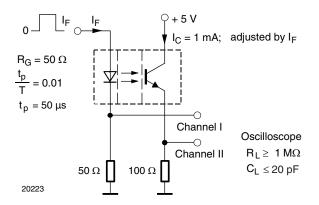


Figure 1. Test Circuit for ton and toff

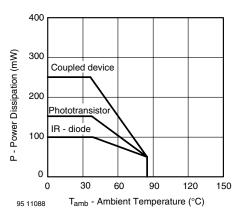


Figure 3. Power Dissipation Limit vs. Ambient Temperature

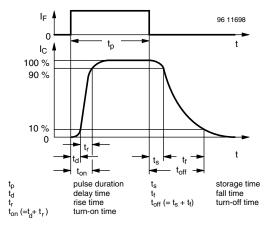


Figure 2. Switching Times

Typical Characteristics

 $T_{amb} = 25$ °C, unless otherwise specified

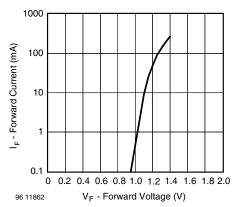


Figure 4. Forward Current vs. Forward Voltage

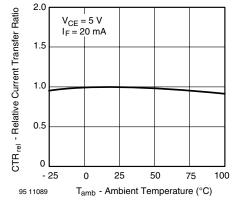


Figure 5. Relative Current Transfer Ratio vs.
Ambient Temperature

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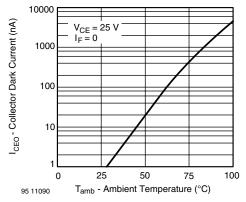


Figure 6. Collector Dark Current vs. Ambient Temperature

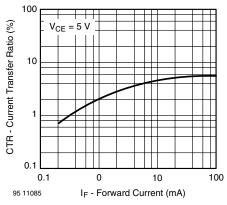


Figure 9. Current Transfer Ratio vs. Forward Current

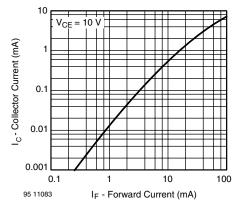


Figure 7. Collector Current vs. Forward Current

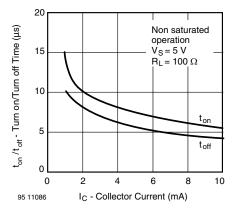


Figure 10. Turn on/off Time vs. Collector Current

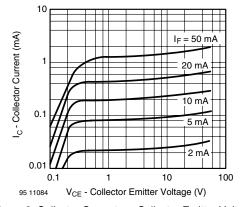


Figure 8. Collector Current vs. Collector Emitter Voltage

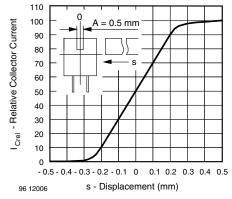
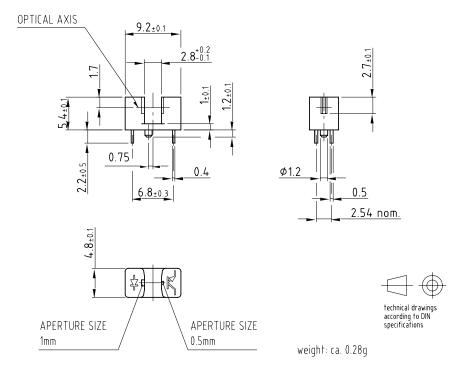


Figure 11. Relative Collector Current vs. Displacement



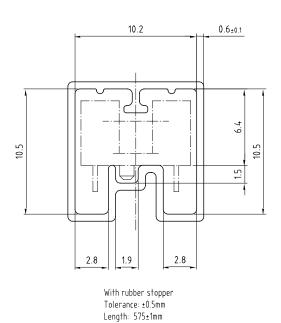


Package Dimensions in mm



Drawing-No.: 6.550-5123.01-4 Issue: 5; 30.01.06

Tube Dimensions



All dimensions in mm

Drawing-No.: 9.700-5245.01-4 Issue: 1; 25.02.00 20256

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Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

> We reserve the right to make changes to improve technical design and may do so without further notice.

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